## NSN 5962-01-382-8117

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Features Provided:
Programmed and electrostatic sensitive
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
C-4 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
4.5 volts applied and 5.5 volts applied
Memory Device Type:
Prom
Hybrid Technology Type:
Monolithic
Special Features:
One time programmable
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883
standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 leadless
Specification Data:
67268-5962-88734033a government standard
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:
Yes - demil/mli
Fiig:
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